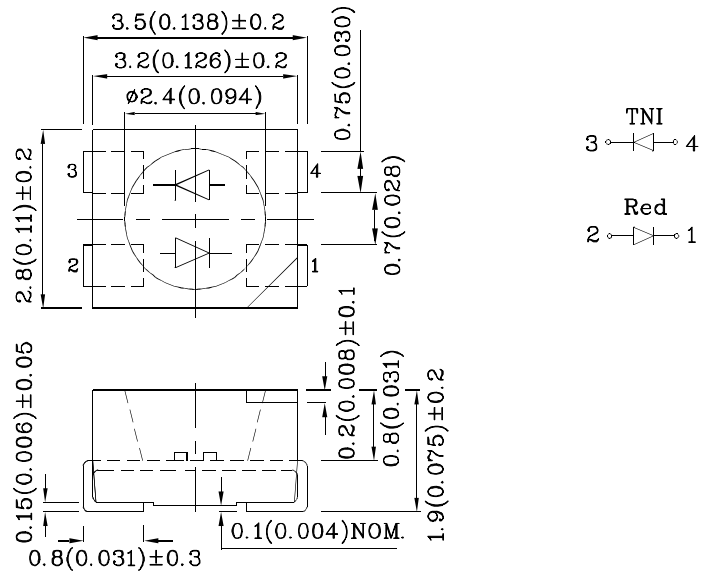


### Features

- Ideal for indication light on hand held products
- Long life and robust package
- Standard Package: 2000pcs/ Reel
- MSL (Moisture Sensitivity Level): 3
- RoHS compliant.



### Package Schematics



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.25(0.01") unless otherwise noted.
3. Specifications are subject to change without notice.

Absolute Maximum Ratings (T <sub>A</sub> =25°C)		Red (AlGaInP)	Unit
Reverse Voltage	V <sub>R</sub>	5	V
Forward Current	I <sub>F</sub>	50	mA
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	i <sub>FS</sub>	150	mA
Power Dissipation	P <sub>D</sub>	125	mW
Operating Temperature	T <sub>A</sub>	-40 ~ +85	°C
Storage Temperature	T <sub>stg</sub>	-40 ~ +85	

A Relative Humidity between 40% and 60% is recommended in ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)

Operating Characteristics (T <sub>A</sub> =25°C)		Red (AlGaInP)	Unit
Forward Voltage (Typ.) (I <sub>F</sub> =20mA)	V <sub>F</sub>	2.1	V
Forward Voltage (Max.) (I <sub>F</sub> =20mA)	V <sub>F</sub>	2.5	V
Reverse Current (Max.) (V <sub>R</sub> =5V)	I <sub>R</sub>	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I <sub>F</sub> =20mA)	λ <sub>P</sub>	660*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) (I <sub>F</sub> =20mA)	λ <sub>D</sub>	640*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =20mA)	Δλ	20	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	C	45	pF

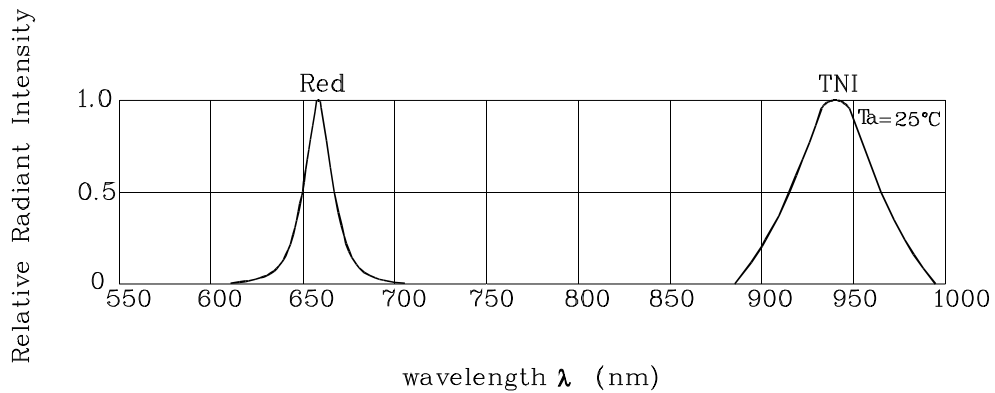
Part Number	Emitting Color	Emitting Material	Lens-color	Luminous Intensity CIE127-2007* (P <sub>o</sub> =mW/sr) @20mA		Wavelength CIE127-2007* nm λ <sub>P</sub>	Viewing Angle 2 θ 1/2
				min.	typ.		
XZM2MRTNI45SC2C	Red	AlGaInP	Water Clear	-	-	400 120*	120°
	-	GaAs		2 1.2*	3.8 2.3*	597 228*	

\*Luminous/Radiant intensity value and wavelength are in accordance with CIE127-2007 standards.

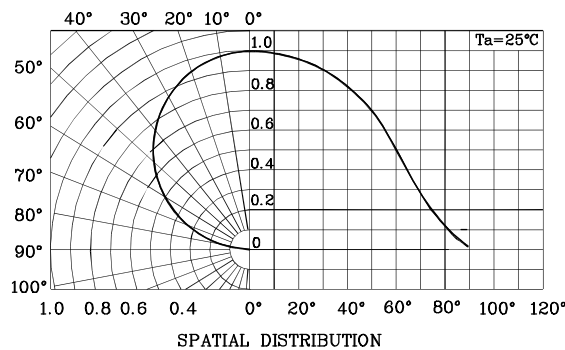
Absolute Maximum Ratings (T <sub>A</sub> =25°C)		TNI (GaAs)	Unit
Reverse Voltage	V <sub>R</sub>	5	V
Forward Current	I <sub>F</sub>	50	mA
Forward Current (Peak) 1/100 Duty Cycle 10us Pulse Width	i <sub>FS</sub>	1200	mA
Power Dissipation	P <sub>D</sub>	80	mW
Operating Temperature	T <sub>A</sub>	-40 ~ +85	°C
Storage Temperature	T <sub>stg</sub>	-40 ~ +85	

A Relative Humidity between 40% and 60% is recommended in ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)

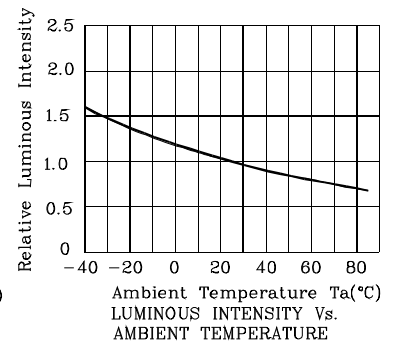
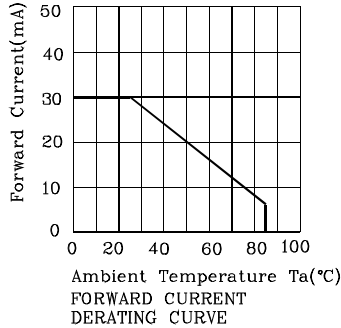
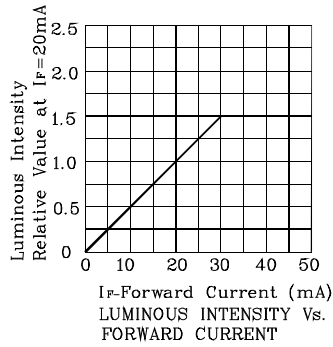
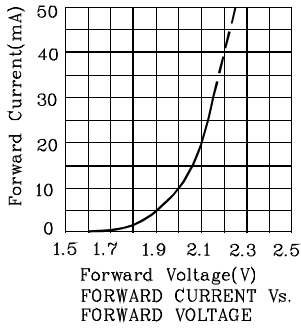
Operating Characteristics (T <sub>A</sub> =25°C)		TNI (GaAs)	Unit
Forward Voltage (Typ.) (I <sub>F</sub> =20mA)	V <sub>F</sub>	1.2	V
Forward Voltage (Max.) (I <sub>F</sub> =20mA)	V <sub>F</sub>	1.6	V
Reverse Current (Max.) (V <sub>R</sub> =5V)	I <sub>R</sub>	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I <sub>F</sub> =20mA)	λ <sub>P</sub>	940*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =20mA)	Δλ	50	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	C	90	pF



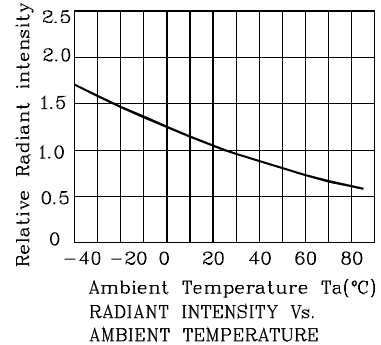
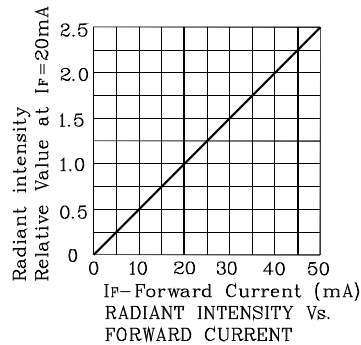
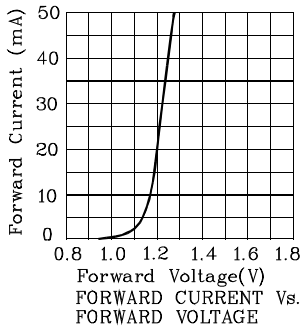
RELATIVE INTENSITY vs. CIE WAVELENGTH



❖ Red

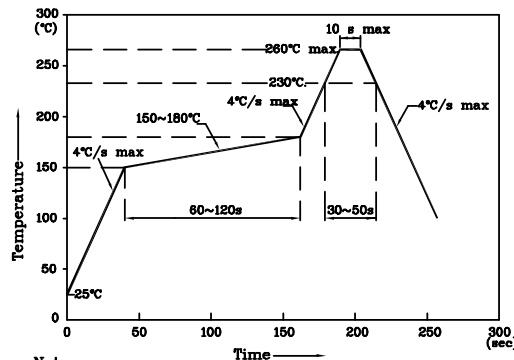


❖ TNI



LED is recommended for reflow soldering and soldering profile is shown below.

Reflow Soldering Profile for SMD Products (Pb-Free Components)

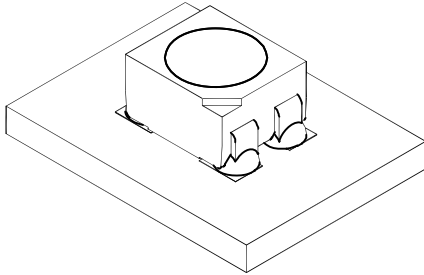


Notes:

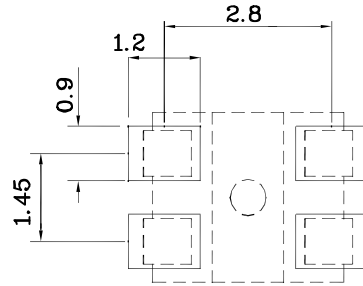
1. Maximum soldering temperature should not exceed 280°C
2. Recommended reflow temperature: 145°C-280°C
3. Do not put stress to the epoxy resin during high temperatures conditions



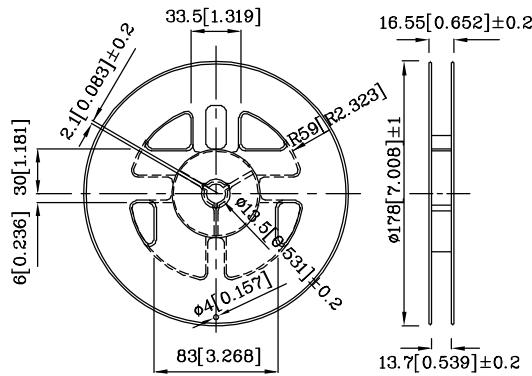
❖ The device has a single mounting surface.  
The device must be mounted according to the specifications.



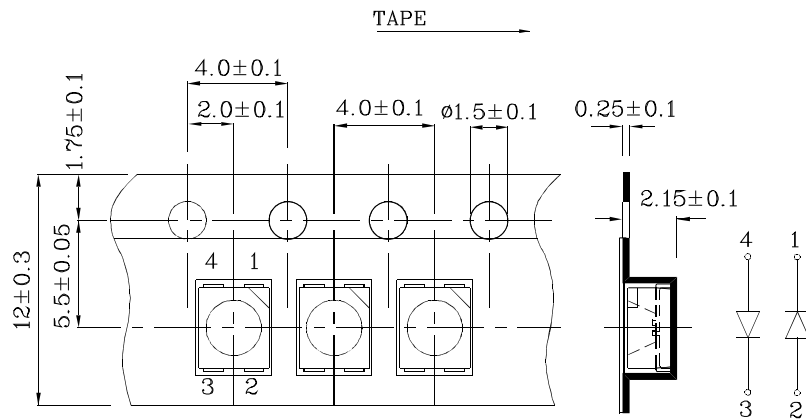
❖ Recommended Soldering Pattern  
(Units : mm; Tolerance: ± 0.1)



❖ Reel Dimension



❖ Tape Specification (Units : mm)



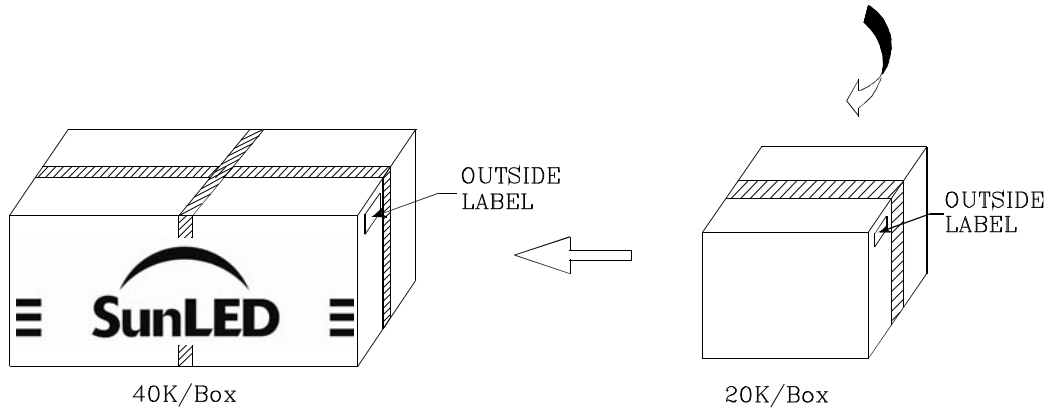
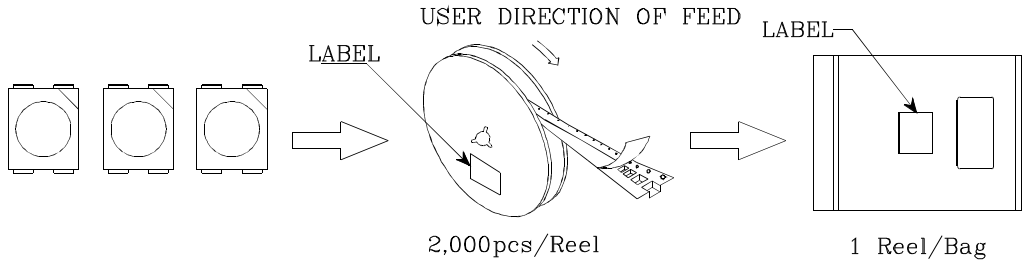
Remarks:


If special sorting is required (e.g. binning based on forward voltage, Luminous intensity / luminous flux, or wavelength), the typical accuracy of the sorting process is as follows:

1. Wavelength: +/-1nm
2. Luminous intensity / luminous flux: +/-15%
3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.

**PACKING & LABEL SPECIFICATIONS**






Q.C.

Q C

XX XX XXXX

PASSED

P/NO : XZxxx45x	
QTY : 2,000 pcs	CODE: XXX
S/N : XX	
LOT NO :	
 XXXXXXXXXXXXXXXXXXXXXXXXXXXX	
RoHS Compliant	

**TERMS OF USE**

1. Data presented in this document reflect statistical figures and should be treated as technical reference only.
2. Contents within this document are subject to improvement and enhancement changes without notice.
3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet. User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
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